

1111C/P (.110" x .110")

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◆ Product Features

High Q, High Power, Low ESR/ESL, Low Noise, High Self-Resonance,

Ultra- Stable Performance.

◆ Product Application

Typical Functional Applications: Bypass, Coupling, Tuning, Feedback, Impedance Matching and D.C. Blocking.

Typical Circuit Applications: UHF/Microwave RF Power Amplifiers, Mixers, Oscillators, Low Noise Amplifiers,

Filter Networks, Timing Circuits and Delay Lines

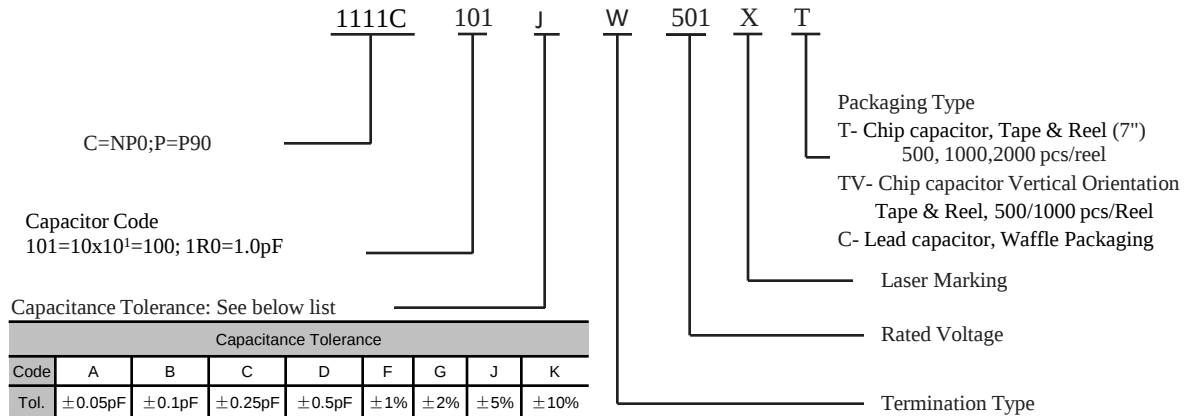


◆ 1111C/P Capacitance Table NP0=C; P90=P Max. capacitance: 1111C 10,000pF ; 1111P 1,000pF

Cap. pF	Code	Tol.	Rated WVDC	Cap. pF	Code	Tol.	Rated WVDC	Cap. pF	Code	Tol.	Rated WVDC	Cap. pF	Code	Tol.	Rated WVDC
0.1	OR1	A,B,		3.6	3R6			43	430			510	511		100V Code 101 or 200V Code 201
0.2	OR2			3.9	3R9			47	470			560	561		
0.3	OR3			4.3	4R3			51	510			620	621		
0.4	OR4			4.7	4R7			56	560			680	681		
0.5	OR5	A,B, C,D	500V Code 501 or 1500V Code 152	5.1	5R1	A,B, C,D		62	620	F,G, J,K		750	751		200V Code 201
0.6	OR6			5.6	5R6			68	680			820	821		
0.7	OR7			6.2	6R2			75	750			910	911		
0.8	OR8			6.8	6R8			82	820			1000	102		
0.9	OR9			7.5	7R5	F,G, J,K	500V Code 501 or 1500V Code 152	91	910			1100	112		200V Code 201
1.0	1R0			8.2	8R2			100	101			1200	122		
1.1	1R1			9.1	9R1			110	111			1500	152		
1.2	1R2			10	100			120	121			1800	182		
1.3	1R3			11	110			130	131			2200	222	F,G, J,K	100V Code 101
1.4	1R4			12	120			150	151			2700	272		
1.5	1R5			13	130			160	161			3000	302		
1.6	1R6			15	150			180	181			3300	332		
1.7	1R7			16	160			200	201			3900	392		50V Code 500
1.8	1R8			18	180			220	221			4700	472		
1.9	1R9			20	200			240	241			5100	512		
2.0	2R0			22	220			270	271			5600	562		
2.1	2R1			24	240			300	301			10000	103		
2.2	2R2			27	270			330	331						
2.4	2R4			30	300			360	361						
2.7	2R7			33	330			390	391						
3.0	3R0			36	360			430	431						
3.3	3R3			39	390			470	471						

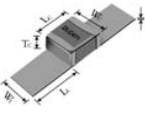
Remark: special capacitance, tolerance and WVDC are available, consult with PASSIVE PLUS.

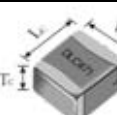
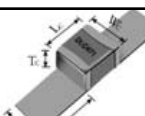
◆ Part Numbering



◆ 1111C/P Lead Type and Dimensions

unit:inch(millimeter)

Series	Term. Code	Type/ Outlines	Capacitor Dimensions				Overlap and Lead Dimensions			Plated Material
			Length Lc	Width Wc	Thick. Tc	Overlap B	Length LL	Width WL	Thickness TL	
1111C 1111P	W	 Chip	.110 +.020 to -.010 (2.79 +0.51 to -.25)	.110 ±.010 (2.79± 0.25)	.10 (2.54) max	.024 (0.60) Max	-	-	-	Plated Nickel Plated 100%Sn, RoHS Compliant
1111C 1111P	MS	 Microstrip	.135 ±.015 (3.43± 0.38)	.110 ±.010 (2.79± 0.25)	.10 (2.54) max	-	.250 (6.35) min	.093 ±.005 (2.36 ±0.13)	.008±.001 (0.2±0.025)	Silver- plated Copper
									.004±.001 (0.1±0.025)	100%Silver

Series	Term. Code	Type/ Outlines	Capacitor Dimensions				Overlap and Lead Dimensions			Plated Material
			Length Lc	Width Wc	Thick. Tc	Overlap B	Length LL	Width WL	Thickness TL	
1111C 1111P	P	 Chip (non-mag)	.110 +.020 to -.010 (2.79 +0.51to -.25)	.110 ±.010 (2.79± 0.25)	.10 (2.54) max	.024 (0.60) Max	-	-	-	Copper Plated 100%Sn, RoHS Compliant
1111C 1111P	MN	 Microstrip (non-mag)	.135 ±.015 (3.43± 0.38)	.110 ±.010 (2.79± 0.25)	.10 (2.54) max	-	.250 (6.35) min	.093 ±.005 (2.36± 0.13)	.008±.001 (0.2±0.025)	Silver- plated Copper
									.004±.001 (0.1±0.025)	100%Silver

Note: non-mag is no magnetism.

◆ Performance

Item	Specifications
Quality Factor (Q)	greater than 10000 at 1MHz.
Insulation Resistance (IR)	0.1 pF to 470 pF: 10 ⁶ Megohms min. @ +25 °C at rated WVDC. 10 ⁵ Megohms min. @ +125 °C at rated WVDC. 510 pF to 10000 pF: 10 ⁵ Megohms min. @ +25 °C at rated WVDC. 10 ⁴ Megohms min. @ +125 °C at rated WVDC.
Rated Voltage	See Rated Voltage Table.
Dielectric Withstanding Voltage (DWV)	250% of Voltage for 5seconds, Rated Voltage ≤ 500VDC 150% of Voltage for 5 seconds, 500VDC < Rated Voltage ≤ 1250VDC 120% of Voltage for 5 seconds, Rated Voltage > 1250VDC
Operating Temperature Range	0.1pF to 330pF ≤ 500V: -55 °C to +175 °C, Other: -55 °C to +125 °C
Temperature coefficient (TC)	C: 0 ± 30ppm/°C; P: +90 ± 20ppm/°C;
Capacitance Drift	± 0.02% or ± 0.02pF, whichever is greater.
Piezoelectric Effects	None
Termination Type	See Termination Type Table.

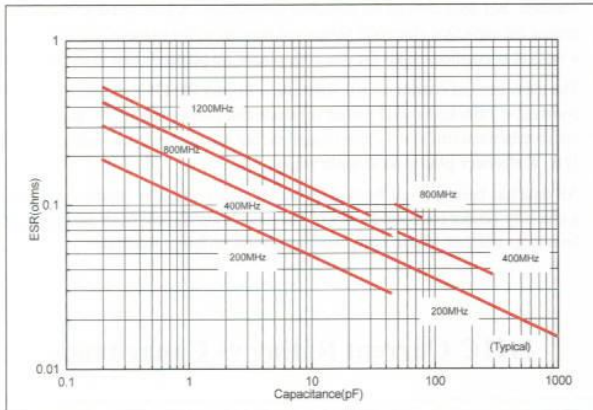
Capacitors are designed and manufactured to meet the requirements of MIL-PRF-55681 and MIL-PRF-123.

◆ Environmental Tests

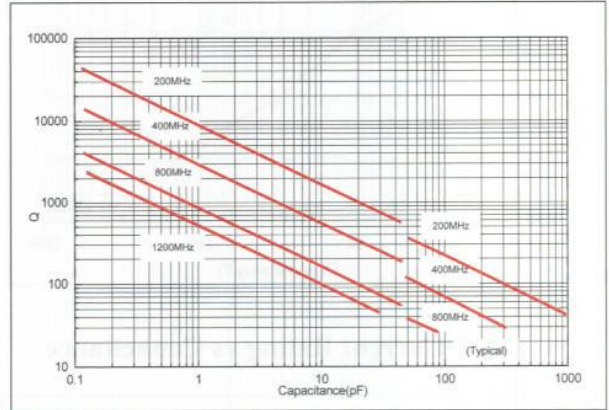
Item	Specifications	Method
Thermal shock	DWV: the initial value IR: Shall not be less than 30% of the initial value Capacitance change: no more than 0.5% or 0.5pF, whichever is greater.	MIL-STD-202, Method 107, Condition A. At the maximum rated temperature(-55°C and 125°C) stay 30min, The time of removing shall not be more than 3 minutes. Perform the five cycles.
Moisture resistance		MIL-STD-202, Method 106.
Humidity (steady state)	DWV: the initial value IR: the initial value Capacitance change: no more than 0.3% or 0.3pF, whichever is greater.	MIL-STD-202, Method 103, Condition A, With 1.5 Volts D.C. applied while subjected to an environment of 85°C with 85% relative humidity for 240 hours minimum.
Life	IR: Shall not be less than 30% of the initial value Capacitance change: no more than 2.0% or 0.5pF, whichever is greater.	MIL-STD-202, Method 108, for 2000 hours, at 125°C, 200% of Voltage for Capacitors, Rated Voltage ≤ 500VDC; 120% of Voltage for Capacitors, 500VDC < Rated Voltage ≤ 1250VDC; 100% of Voltage for Capacitors, Rated Voltage > 1250VDC.

◆ 1111C/P Performance Curve

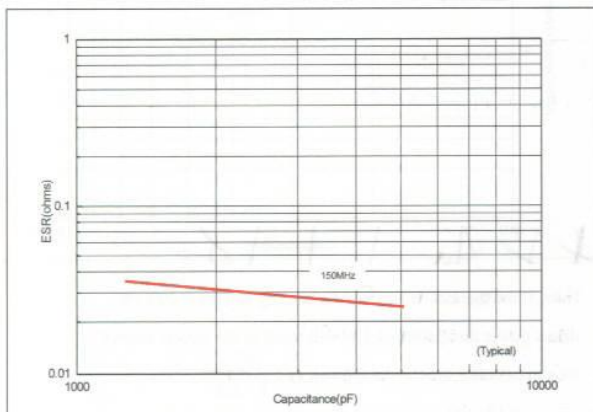
1111C/P ESR vs Capacitance



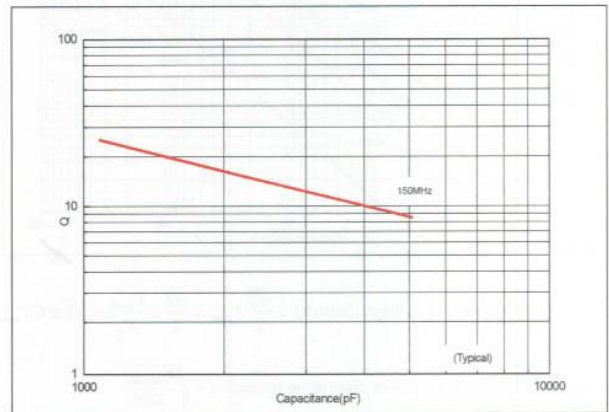
1111C/P Q vs Capacitance



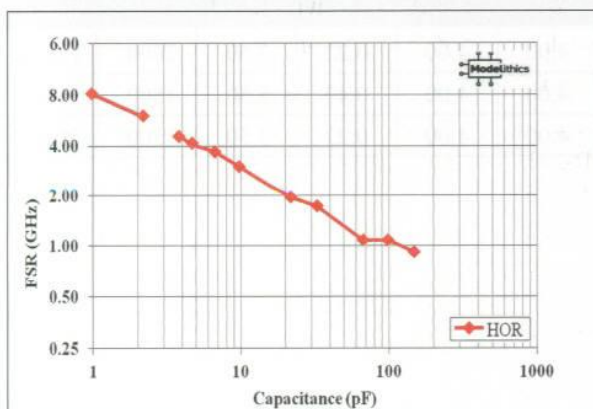
1111C ESR vs Capacitance



1111C Q vs Capacitance



1111C/P Horizontal First Series Resonance(FSRs)



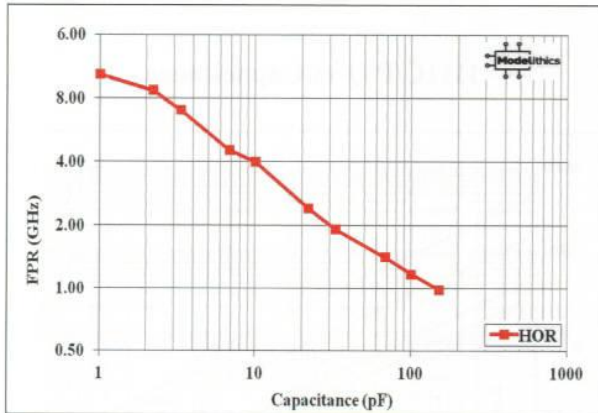
Definitions and Measurement Conditions

For a capacitor in a series configuration, i.e., mounted across a gap in a microstrip trace, with 50-Ohm source and termination resistances, the First Series Resonance, FSR, is defined as the lowest frequency at which the imaginary part of the input impedance, $\text{Im}[Z_{in}]$, equals zero. Should $\text{Im}[Z_{in}]$ or the real part of the input impedance, $\text{Re}[Z_{in}]$, not be monotonic with frequency at frequencies lower than those at which $\text{Im}[Z_{in}] = 0$, the FSR shall be considered as undefined (gap in plot above). FSR is dependent on internal capacitor structure; substrate thickness and dielectric constant; capacitor orientation, as defined above; and mounting pad dimensions.

The measurement conditions are: substrate -- Rogers RO4350; substrate dielectric constant = 3.66; horizontal mount substrate thickness (mils) = 50; gap in microstrip trace (mils) = 72; horizontal mount microstrip trace width (mils) = 110. **Reference planes at sample edges.**

All data has been derived from electrical models created by Modelithics, Inc., a specialty vendor contracted by PPI. The models are derived from measurements on a large number of parts disposed on several different substrates.

1111C/P Horizontal First Parallel Resonance(FPRs)



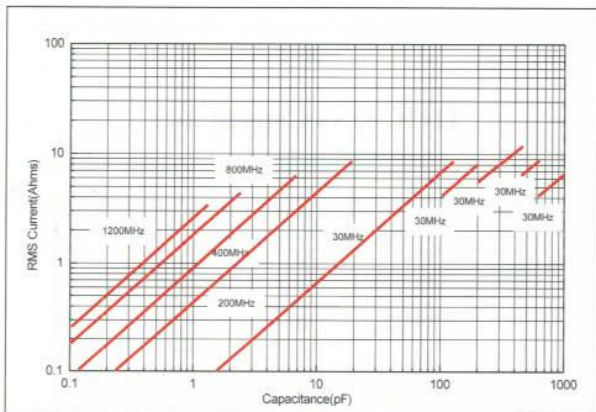
Definitions and Measurement conditions:

For a capacitor in a series configuration, i.e., mounted across a gap in a microstrip trace, with 50-Ohm source and termination resistances, the First Parallel Resonance, FPR, is defined as the lowest frequency at which a suckout or notch appears in |S21|. It is generally independent of substrate thickness or dielectric constant, but does depend on capacitor orientation. A horizontal orientation means the capacitor electrode planes are parallel to the plane of the substrate; a vertical orientation means the electrode planes are perpendicular to the substrate.

The measurement conditions are: substrate -- Rogers RO4350; substrate dielectric constant = 3.66; horizontal mount substrate thickness (mils) = 50; gap in microstrip trace (mils) = 72; horizontal mount microstrip trace width (mils) = 110. **Reference planes at sample edges.**

All data has been derived from electrical models created by Modelithics, Inc., a specialty vendor contracted by PPI. The models are derived from measurements on a large number of parts disposed on several different substrates.

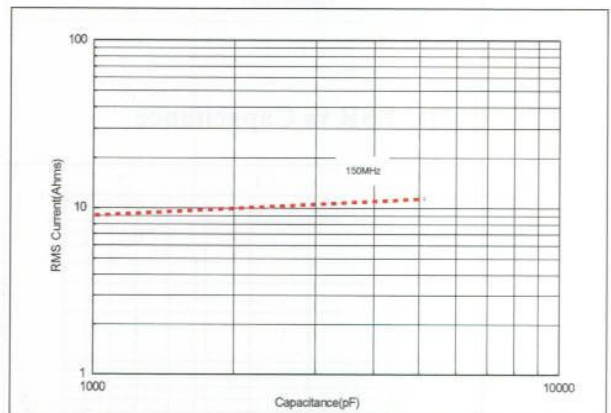
1111C/P Current Rating vs Capacitance



The current depends on voltage limited: $I = \frac{\sqrt{2}}{2} I_{peak} = \frac{\sqrt{2}}{2} \times \frac{V_{rated}}{X_c} = \sqrt{2} \pi f C V_{rated}$

The current depends on power dissipation limited: $I = \sqrt{\frac{P_{dissipation}}{ESR}}$

1111C Current Rating vs Capacitance



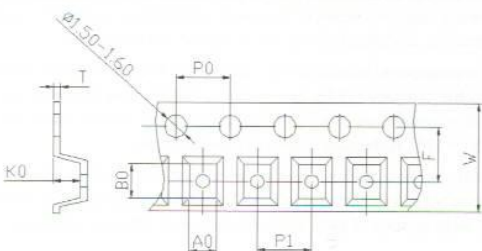
Note: If the thermal resistance of mounting surface is 20°C/W.

then a power dissipation of 3 W will result in the current limited

we can calculate the current limited $I = \sqrt{\frac{P_{dissipation}}{ESR}}$

◆ Tape & Reel Specifications

Orientation	EIA	A0	B0	K0	W	P0	P1	T	F	Qty/reel	Tape Material
Horizontal	1111	2.85	3.90	1.95	8.00	4.00	4.00	0.22	3.50	2000	Plastic
Vertical	1111	2.00	3.50	2.70	12.00	4.00	4.00	0.40	5.50	1500	Plastic
Vertical	1111	2.96	3.60	2.40	8.00	4.00	4.00	0.22	3.50	1500	Plastic



◆ Design Kits

These capacitors are 100% RoHS. Kits are available in Magnetic and Non-Magnetic that contain 10 (ten) pieces per value; 16 values per kit.

Design Kit	Description	Values (pF)	No. of values	Tolerances
DKD1111C01 DKD1111P01	1.0pF - 10pF	1.0, 1.2, 1.5, 1.8, 2.0, 2.2, 2.4, 2.7, pF	16	± 0.1pF
		3.0,3.3,3.9, 4.7, 5.6, 6.8, 8.2pF		± 0.25pF
		10pF		± 5%
DKD1111C02 DKD1111P02	10pF -100pF	10, 12, 15, 18, 20, 22, 24, 27, 30, 33, 39, 47, 56, 68, 82, 100pF	16	± 5%
DKD1111C03 DKD1111P03	100pF-1000pF	100, 120, 150, 180, 200, 220, 240, 270, 300, 330, 390, 470, 560, 680, 820,1000 pF	16	± 5%
DKD1111C04 DKD1111P04	1000pF-10000pF	1000, 1100, 1200, 1500, 1800, 2200, 2700, 3000, 3300, 3900, 4700, 5100, 5600, 10000 pF	14	± 5%
DKD1111C05 DKD1111P05	1.0pF - 10pF Non-magnetic	1.0, 1.2, 1.5, 1.8, 2.0, 2.2, 2.4, 2.7, pF	16	± 0.1pF
		3.0,3.3,3.9, 4.7, 5.6, 6.8, 8.2pF		± 0.25pF
		10pF		± 5%
DKD1111C06 DKD1111P06	10pF - 100pF Non-magnetic	10, 12, 15, 18, 20, 22, 24, 27, 30, 33, 39, 47, 56, 68, 82, 100pF	16	± 5%
DKD1111C07 DKD1111P07	100pF- 1000pF Non-magnetic	100, 120, 150, 180, 200, 220, 240, 270, 300, 330, 390, 470, 560, 680, 820,1000 pF	16	± 5%
DKD1111C08 DKD1111P08	1000pF- 10000pF Non-magnetic	1000, 1100, 1200, 1500, 1800, 2200, 2700, 3000, 3300, 3900, 4700, 5100, 5600, 10000 pF	14	± 5%

